



New Product

DG2303

Vishay Siliconix

High-Speed, Low r_{ON} , 1.8-V/2.5-V/3.3-V/5-V, SPST Analog Switch (1-Bit Bus Switch)

FEATURES

- SC-70 5-Lead Package
- 5- Ω Switch Connection Between Two Ports
- Minimal Propagation Delay Through The Switch
- Low I_{CC}
- Zero Bounce In Flow-Through Mode
- Control Inputs Compatible with TTL Level

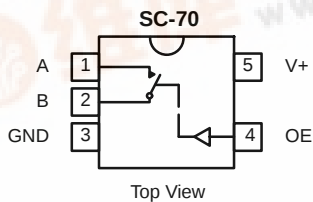
DESCRIPTION

The DG2303 is a high-speed, 1-bit, low power, TTL-compatible bus switch. Using sub-micron CMOS technology, DG2303 achieves low on-resistance and negligible propagation delay.

The DG2303 consist of a bi-directional input/output pins A

and B. When the output enable (OE) is low, the input/output pins are connected. When the OE is high, the switch is open and a high-impedance state exists between input/output pins A and B.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: E6

TRUTH TABLE

OE	B	Function
L	HiZ State	Disconnect
H	A	Connect

ORDERING INFORMATION

Temp Range	Package	Part Number
-40 to 85°C	SC70-5	DG2303DL

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ABSOLUTE MAXIMUM RATINGS

Reference to GND

V+	-0.3 to +6 V
OE, A, B ^a	-0.3 to (V+ + 0.3 V)
Continuous Current (Any terminal)	± 50 mA
Peak Current (Pulsed at 1 ms, 10% duty cycle)	± 200 mA
Storage Temperature (D Suffix)	-65 to 150°C

Power Dissipation (Packages)^b

5-Pin SC70 ^c	250 mW
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Notes:

- Signals on A, or B or OE exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 3.1 mW/°C above 70°C

SPECIFICATIONS (V+ = 5.0 V)							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 1.65 V to 5.5 V, V _{IN} = V _{IH} or V _{IL} ^e	Temp ^a	Limits -40 to 85°C			Unit
				Min ^b	Typ ^c	Max ^b	
DC Characteristics							
On-Resistance	r _{ON}	V+ = 1.8 V, V _A = 0 V, I _B = 4 mA	Full			28.0	Ω
		V+ = 1.8 V, V _A = 1.8 V, I _B = 4 mA	Full			60.0	
		V+ = 2.3 V, V _A = 0 V, I _B = 8 mA	Full			12.0	
		V+ = 2.3 V, V _A = 2.3 V, I _B = 8 mA	Full			30.0	
		V+ = 3.0 V, V _A = 0 V, I _B = 24 mA	Full			9.0	
		V+ = 3.0 V, V _A = 3.0 V, I _B = 24 mA	Full			20.0	
		V+ = 4.5 V, V _A = 0 V, I _B = 30 mA	Full			7.0	
		V+ = 4.5 V, V _A = 2.4 V, I _B = 15 mA	Full			12.0	
		V+ = 4.5 V, V _A = 4.5 V, I _B = 30 mA	Full			15.0	
r _{ON} Flatness ^d	r _{ON} Flatness	V+ = 1.8 V, V _A = 0 V to V+, I _B = 4 mA	Full		125		
		V+ = 2.5 V, V _A = 0 V to V+, I _B = 8 mA	Full		28		
		V+ = 3.3 V, V _A = 0 V to V+, I _B = 24 mA	Full		12		
		V+ = 5.0 V, V _A = 0 V to V+, I _B = 30 mA	Full		6		
Switch Off Leakage Current	I _(off)	V+ = 5.5 V, V _A = 1 V/4.5 V, V _B = 4.5 V/1 V	Full	-10		10	μA
Switch-On Leakage Current	I _(on)	V+ = 5.5 V, V _A = V _B = 1 V/4.5 V	Full	-10		10	
Input High Voltage	V _{IH}	V+ = 1.65 V to 1.95 V	Full	1.35			V
		V+ = 2.3 V to 2.7 V	Full	1.6			
		V+ = 3.0 V to 3.6 V	Full	2.0			
		V+ = 4.5 V to 5.5 V	Full	2.4			
Input Low Voltage	V _{IL}	V+ = 1.65 V to 1.95 V	Full			0.4	
		V+ = 2.3 V to 2.7 V	Full			0.4	
		V+ = 3.0 V to 3.6 V	Full			0.6	
		V+ = 4.5 V to 5.5 V	Full			0.8	
Input Current	I _{IL} or I _{IH}	V _{OE} = 0 or V+	Full	-1		1	μA
Dynamic Characteristics							
Prop Delay Bus-to-Bus ^f	t _{PHL} , t _{PLH}	V _{LD} = Open, V= 1.65 V to 1.95 V, (Figure 1 and 2)	Full			5	ns
		V _{LD} = Open, V= 2.3 V to 2.7 V, (Figure 1 and 2)	Full			2	
		V _{LD} = Open, V= 3.0 V to 3.6 V, (Figure 1 and 2)	Full			1	
		V _{LD} = Open, V= 4.5 V to 5.5 V, (Figure 1 and 2)	Full			1	



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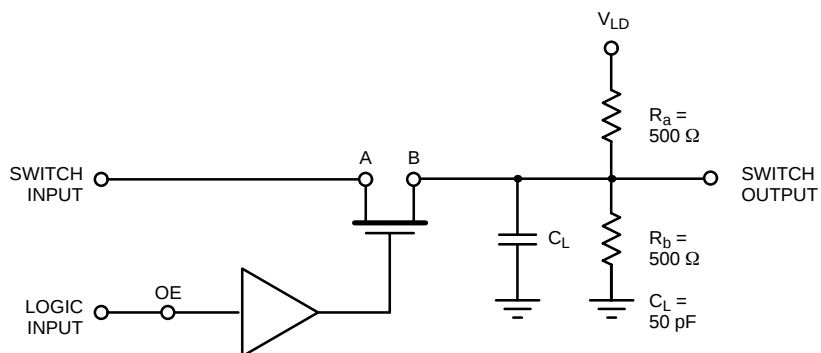
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 1.65 V to 5.5 V, VIN = VIH or VIL ^e	Temp ^a	Limits -40 to 85°C			Unit
				Min ^b	Typ ^c	Max ^b	
Dynamic Characteristics							
Output Enable Time ^d	tPZL	V _{LD} = 2 x V+, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		4.2		ns
		V _{LD} = 2 x V+, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		3.3		
		V _{LD} = 2 x V+, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		2.6		
		V _{LD} = 2 x V+, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		1.8		
	tPZH	V _{LD} = 0 V, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		4.4		
		V _{LD} = 0 V, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		3.3		
		V _{LD} = 0 V, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		2.7		
		V _{LD} = 0 V, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		2.0		
Output Disable Time ^d	tPLZ	V _{LD} = 2 x V+, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		14.3		ns
		V _{LD} = 2 x V+, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		10.5		
		V _{LD} = 2 x V+, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		8.6		
		V _{LD} = 2 x V+, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		7.4		
	tPHZ	V _{LD} = 0 V, V+ = 1.65 V to 1.95 V (Figure 1 and 2)	Full		10.7		
		V _{LD} = 0 V, V+ = 2.3 V to 2.7 V (Figure 1 and 2)	Full		9.6		
		V _{LD} = 0 V, V+ = 3.0 V to 3.6 V (Figure 1 and 2)	Full		8.7		
		V _{LD} = 0 V, V+ = 4.5 V to 5.5 V (Figure 1 and 2)	Full		7.5		
Charge Injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω, (Figure 3)	Room		0.5		pC
Off Isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 10 MHz	Room		-50		dB
Insertion Loss ^d	Loss	RL = 50 Ω	Room		>200		MHz
Input Capacitance ^d	Cin	VOE = 0 or V+, f = 1 MHz	Room		4		pF
Channel-Off Capacitance ^d	C(off)		Room		9		
Channel-On Capacitance ^d	CON		Room		20		
Power Supply							
Power Supply Range	V+			1.65		5.5	V
Power Supply Current	I+	VOE = 0 or V+				1.0	μA

Notes:

- Room = 25°C, Full = as determined by the operating suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for design aid only, not guaranteed nor subject to production testing.
- Guarantee by design, nor subjected to production test.
- V_{IN} = input voltage to perform proper function.
- Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch.



AC LOADING AND WAVEFORMS



Input driven by 50-Ω source terminated in 50 Ω
 C_L includes load and stray capacitance
Input PRR = 1.0 MHz, $t_W = 50$ ns

Figure 1. AC Test Circuit

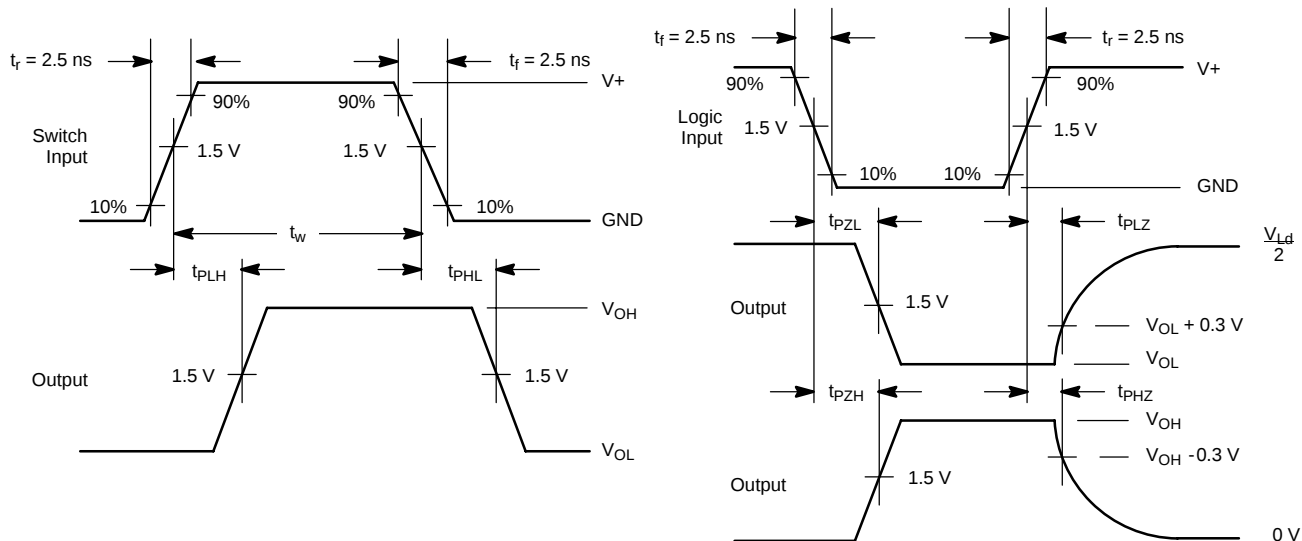


Figure 2. AC Waveforms



TEST CIRCUITS

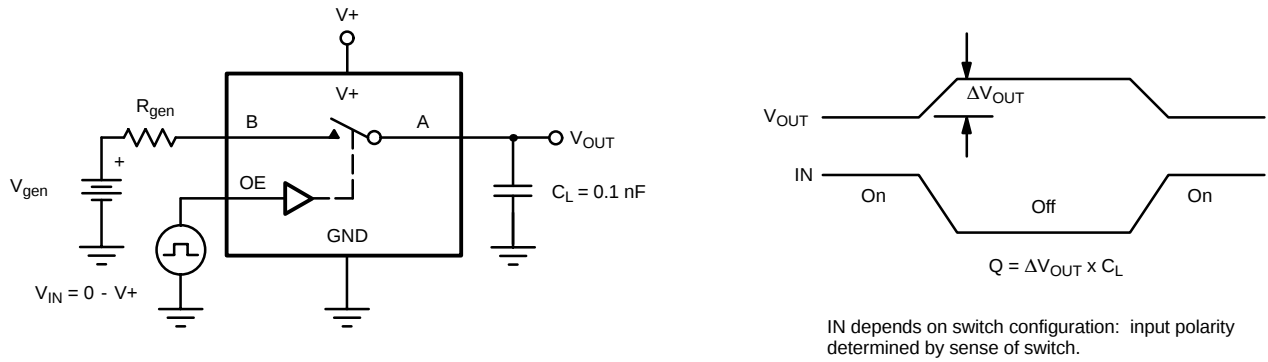


Figure 3. Charge Injection

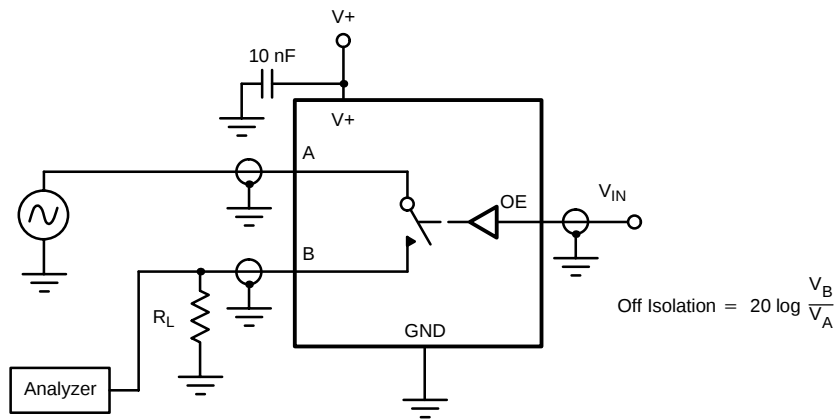


Figure 4. Off-Isolation

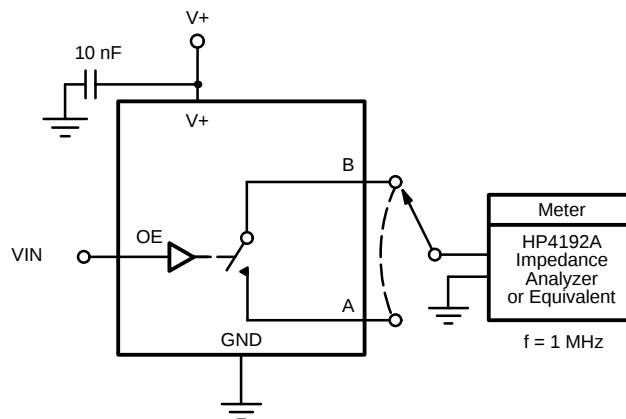


FIGURE 5. Channel Off/On Capacitance